

SP691A/693A/800L/800M

Low Power Microprocessor Supervisory with Battery Switch-Over

FEATURES

- Precision 4.65V/4.40V Voltage Monitoring
- 200ms Or Adjustable Reset Time
- 100ms, 1.6s Or Adjustable Watchdog Time
- 60µA Maximum Operating Supply Current
- 2.0µA Maximum Battery Backup Current
- 0.1µA Maximum Battery Standby Current
- Power Switching
 250mA Output in Vcc Mode (0.6Ω)
 25mA Output in Battery Mode (5Ω)
- On-Board Gating of Chip-Enable Signals Memory Write-Cycle Completion 6ns CE Gate Propagation Delay
- Voltage Monitor for Power-Fail or Low Battery
- Backup-Battery Monitor
- RESET Valid to Vcc=1V
- 1% Accuracy Guaranteed (SP800L/800M)
- Pin Compatible Upgrade to MAX691A/693A/ 800L/800M



Now Available in Lead Free Packaging

- DESCRIPTION

The **SP691A/693A/800L/800M** is a microprocessor (μ P) supervisory circuit that integrates a myriad of components involved in discrete solutions to monitor power-supply and battery-control functions in μ P and digital systems. The **SP691A/693A/800L/800M** offers complete μ P monitoring and watchdog functions. The **SP691A/693A/800L/800M** is ideal for a low-cost battery management solution and is well suited for portable, battery-powered applications with its supply current of 35μ A. The 6ns chip-enable propagation delay, the 25mA current output in battery-backup mode, and the 250mA current output in standard operation also makes the **SP691A/693A/800L/800M** suitable for larger scale, high-performance equipment.

Part Number	RESET Threshold	RESET Accuracy	PFI Accuracy	Backup-Battery Switch
SP691A	4.65V	<u>+</u> 125mV	<u>+</u> 4%	YES
SP693A	4.40V	<u>+</u> 125mV	<u>+</u> 4%	YES
SP800L	4.65V	<u>+</u> 50mV	<u>+</u> 1%	YES
SP800M	4.40V	<u>+</u> 50mV	<u>+</u> 1%	YES

These are stress ratings only and functional operation of the device at these ratings or any other above those indicated in the operation sections of the specifications below is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

Terminal Voltages	(with respect to GND)	
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V _{cc}	0.3V to +6V
V	0.3V to +6V
All Other Inputs	0.3V to (V _{cc} +0.3V)
Input Currents	
V_ Peak	1.0A
V _{cc} Continuous	250mA
V	
V _{PATT} Continuous	
GND, BATT ON	100mA
All Other Inputs	
•	

ABSOLUTE MAXIMUM RATINGS

Enhanced ESD 3	Specifications	+4kV Human	Body Model
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Power Dissipation Per Package

16-pin PDIP (derate 14.3mW/°C above +70°C)	1150mW
16-pin Narrow SOIC (derate 13.6mW/°C above 70°C)	1090mW
16-pin Wide SOIC (derate 11.2mW/°C above 70°C)	900mW
,	

Storage Temperature......65°C to +150°C Lead Temperature (soldering,10 sec).....+300°C

ELECTRICAL CHARACTERISTICS

 V_{CC} = +4.75V to +5.5V for the **SP691A/800L**, V_{CC} = +4.5V to +5.5V for the **SP693A/800M**, V_{BATT} = +2.8V, and T_{AMB} = T_{MIN} to T_{MAX} unless otherwise noted. Typical values apply at T_{AMB} = +25°C.

PARAMETERS	MIN.	TYP.	MAX.	UNITS	CONDITIONS
Operating Voltage Range, V_{cc} or V_{BATT} , NOTE 1	0		5.5	V	
Output Voltage, V _{OUT} in Normal Operating Mode	V _{cc} -0.05 V _{cc} -0.3 V _{cc} -0.2	V _{cc} -0.015 V _{cc} -0.15 V _{cc} -0.09		V	$\begin{split} & V_{cc}{=}4.5V, \ I_{out}{=}25mA \\ & V_{cc}{=}4.5V, \ I_{out}{=}250mA \\ & V_{cc}{=}3.0V, \ V_{_{BATT}}{=}2.8V, \ I_{out}{=}100mA \end{split}$
V_{cc} -to- V_{out} On-Resistance		0.6 0.9	1.2 2.0	Ω	V _{cc} =4.5V V _{cc} =3.0V
V _{out} in Battery-Backup Mode	V _{BATT} -0.3 V _{BATT} -0.25 V _{BATT} -0.15	V _{BATT} -0.1 V _{BATT} -0.07 V _{BATT} -0.05		V	$\begin{split} & V_{\text{BATT}} = 4.5V, \ I_{\text{OUT}} = 20mA \\ & V_{\text{BATT}} = 2.8V, \ I_{\text{OUT}} = 10mA \\ & V_{\text{BATT}} = 2.0V, \ I_{\text{OUT}} = 5mA \end{split}$
V _{BATT} -to-V _{OUT} On-Resistance		5 7 10	15 25 30	Ω	V_{BATT} =4.5V V_{BATT} =2.8V V_{BATT} =2.0V
Supply Current in Normal Operating Mode, I _{vcc}		35	60	μΑ	V_{cc} >(V_{BATT} -1V), excluding I _{OUT}
Supply Current in Battery- Backup Mode, I _{BATT} , NOTE 2		0.001	2.0	μΑ	V_{cc} <(V_{BATT} -1.2V), V_{BATT} =2.8V, excluding I _{OUT}
$\rm V_{BATT}$ Standby Current, $\rm I_{BATT},$ NOTE 3	-0.1		0.02	μΑ	$V_{CC} \ge (V_{BATT} + 0.2V)$, excluding I_{OUT}
Battery Switchover Threshold		V _{BATT} +0.03 V _{BATT} -0.03		V	power-up power-down
Battery Switchover Hysteresis		60		mV	Peak to Peak

 $\underbrace{ \textbf{ELECTRICAL CHARACTERISTICS}}_{V_{CC} = +4.75V \text{ to } +5.5V \text{ for the } \textbf{SP693A/800M}, V_{BATT} = +2.8V, \text{ and } T_{AMB} = T_{MIN} \text{ to } T_{MAX} \text{ unless otherwise} }$

PARAMETERS	MIN.	TYP.	MAX.	UNITS	CONDITIONS
BATT ON Output Low Voltage		0.1 0.7	0.4 1.5	V	I _{SINK} =3.2mA I _{SINK} =25mA
BATT ON Output Short		60		mA	sink current
Circuit Current	1	15	100	μΑ	source current
RESET, LOWLINE, AND WAT	CHDOG T	IMER			
Reset Threshold Voltage	4.50	4.65	4.75		SP691A
	4.25	4.40	4.50	V	SP693A
	4.60	4.65	4.70	v	SP800L
	4.35	4.40	4.45		SP800M
Reset Threshold Hysteresis		15		mV	center-to-peak
V _{cc} to RESET Delay		80		μs	power down
LOWLINE to RESET Delay		800		ns	power down
Reset Active Timeout Period for the Internal Oscillator	140	200	280	ms	power-up
Reset Active Timeout Period for the External Clock, NOTE 4		2048		clock cycles	power-up
Watchdog Timeout Period for	1.0	1.6	2.25	sec	long period
the Internal Oscillator	70	100	140	ms	short period
Watchdog Timeout Period for		4096		clock	long period
the External Clock, NOTE 4		1024		cycles	short period
Minimum Watchdog Input Pulse Width	100			ns	V _{IL} =0.8V,V _{IH} =0.75xV _{CC}
RESET Output Voltage		0.004	0.3		I_{SINK} =50 μ A, V _{CC} =1V, V _{CC} falling
		0.1	0.4	V	Ι _{sink} =3.2mA, V _{cc} =4.25V
	3.5				I _{source} =1.6mA, V _{cc} =5V
RESET Output Short-Circuit Current		7	20	mA	output source current
RESET Output Voltage Low, NOTE 5		0.1	0.4	V	I _{SINK} =3.2mA
LOWLINE Output Voltage		0.1	0.4	V	I _{SINK} =3.2mA, V _{CC} =4.25V
	3.5				$I_{SOURCE} = 1\mu A, V_{CC} = 5V$
LOWLINE Output Short Circuit Current		15	100	μΑ	output source current
WDO Output Voltage		0.1	0.4	1/	I _{SINK} =3.2mA
	3.5			V	I_{SOURCE} =500 μ A, V_{CC} =5V
WDO Output Short-Circuit		2	10	m۸	
Current					

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ELECTRICAL CHARACTERISTICS

 $V_{_{CC}}$ = +4.75V to +5.5V for the **SP691A/800L**, $V_{_{CC}}$ = +4.5V to +5.5V for the **SP693A/800M**, $V_{_{BATT}}$ = +2.8V, and $T_{_{AMB}}$ = $T_{_{MIN}}$ to $T_{_{MAX}}$ unless otherwise noted. Typical values apply at $T_{_{AMB}}$ =+25°C.

PARAMETERS	MIN.	TYP.	MAX.	UNITS	CONDITIONS
WDI Threshold Voltage, NOTE 6	$0.75 \mathrm{xV}_{\mathrm{cc}}$		0.8	V	V _{IH} V _{IL}
WDI Input Current	-50	-10		μA	WDI=0V
		20	50		WDI=V _{OUT}
POWER-FAIL COMPARATO	R				
PFI Input Threshold	1.237	1.25	1.263	V	SP691A/693A, V _{cc} =5V SP800L/800M, V = 5V
PFI Leakage Current		+0.01	+25	nA	
PEO Output Voltage		0.1	0.4		L=3.2mA
	3.5	0.11	011	V	$I_{\text{SOURCE}} = 1 \mu A, V_{\text{CC}} = 5 V$
PFO Short Circuit Current		60		mA	output sink current
	1	15	100	μΑ	output source current
PFI-to-PFO Delay		25		us	V _{od} =15mV
		60		pro	V _{oD} =15mV
CHIP-ENABLE GATING	-				
CE _{IN} Leakage Current		<u>+</u> 0.005	<u>+</u> 1	μΑ	disable mode
$\overline{CE_{IN}}$ to $\overline{CE_{OUT}}$ Resistance, NOTE 7		65	150	Ω	enable mode
CE _{OUT} Short-Circuit Current (RESET Active)	0.1	0.75	2.0	mA	disable mode, CE _{OUT} =0V
$\overline{CE_{IN}}$ to $\overline{CE_{OUT}}$ Propagation Delay, NOTE 8		6	10	ns	50 Ω source impedance driver, C _{LOAD} =50pF
CE _{OUT} Output Voltage High (RESET Active)	3.5 2.7			V	V _{cc} =5V, I _{OUT} = 100μA V _{cc} =0V, V _{BATT} =2.8V, I _{OUT} =1μA
RESET to CE _{OUT} Delay		12		μs	power-down
INTERNAL OSCILLATOR	•				·
OSC _{IN} Leakage Current		0.10	<u>+</u> 5.0	μΑ	OSC _{SEL} =0V
OSC _{IN} Input Pull-Up Current		10	100	μΑ	$OSC_{SEL} = V_{OUT}$ or floating, $OSC_{IN} = 0V$
OSC _{SEL} Input Pull-Up Current		10	100	μΑ	OSC _{SEL} =0V
OSC _{IN} Frequency Range		200		kHz	OSC _{SEL} =0V
OSC _{IN} External Oscillator Threshold Voltage	V _{OUT} -0.3	V _{OUT} -0.6 3.65	2.0	V	V _{IH} V _{IL}
OSC _{IN} Frequency with External Capacitor		2		kHz	OSC _{SEL} =0V, C _{OSC} =47pF

 V_{CC} = +4.75V to +5.5V for the **SP691A/800L**, V_{CC} = +4.5V to +5.5V for the **SP693A/800M**, V_{BATT} = +2.8V, and T_{AMB} = T_{MIN} to T_{MAX} unless otherwise noted. Typical values apply at T_{AMB} =+25°C.

NOTE 1: Either V_{cc} or V_{BATT} can go to 0V, if the other is greater than 2.0V.

NOTE 2: The supply current drawn by the **SP691A/693A/800L/800M** from the battery (excluding I_{OUT}) typically goes to 5µA when $(V_{BATT} - 1V) < V_{CC} < V_{BATT}$. In most applications, this is a brief period as V_{CC} falls through this region. NOTE 3: "+" = battery-discharging current, "-" = battery-charging current.

NOTE 4: Although presented as typical values, the number of clock cycles for the reset and watchdog timeout periods are fixed and do not vary with process or temperature.

NOTE 5: RESET is an open-drain output and sinks current only.

NOTE 6: WDI is internally connected to a voltage divider between V_{out} and GND. If unconnected, WDI is driven to 1.6V (typ), disabling the watchdog function.

NOTE 7: The chip-enable resistance is tested with $V_{cc} = +4.75V$ for the **SP691A/800L** and $V_{cc} = +4.5V$ for the **SP693A/800M**. $\overline{CE_{IN}} = \overline{CE_{OUT}} = V_{cc}/2$.

NOTE 8: The chip-enable propagation delay is measured from the 50% point at $\overline{CE_{IN}}$ to the 50% point at $\overline{CE_{OIIT}}$.



Figure 1. V_{cc} Supply Current vs. Temperature (Normal Operating Mode)



Figure 3. Chip-Enable On-Resistance vs. Temperature



Figure 2. Battery Supply Current vs. Temperature (Battery-Backup Mode)





TYPICAL PERFORMANCE CHARACTERISTICS

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Figure 5. V_{CC} to V_{OUT} On-Resistance vs. Temperature



Figure 7. Reset Threshold vs. Temperature



Figure 9. Reset Delay vs. Temperature



Figure 6. PFI Threshold vs. Temperature



Figure 8. RESET Output Resistance vs. Temperature



Figure 10. Battery Current vs. Input Supply Voltage



Figure 11. Watchdog and Reset Timeout Period vs. OSC_{IN} Timing Capacitor (C_{OSC})



Figure 13. V_{CC} to V_{OUT} vs. Output Current (Normal Operating Mode)



Figure 12. Chip-Enable Propagation Delay vs. $\overline{CE_{_{OUT}}}$ Load Capacitance



Figure 14. V_{BATT} to V_{OUT} vs. Output Current (Battery-Backup Mode)



Figure 15. V_{cc} to $\overline{LOWLINE}$ and $\overline{CE_{out}}$ Delay

PINOUT



PIN ASSIGNMENTS

- Pin 1 V_{BATT} Battery-Backup Input. Connect to the external battery supply or supercharging capacitor and charging circuit. If a backup battery is not provided, connect this pin to ground.
- Pin 2 V_{out} Output Supply Voltage. V_{out} connects to V_{cc} when V_{cc} is greater than V_{BATT} and V_{cc} is above the reset threshold. When V_{cc} falls below V_{BATT} and V_{cc} is below the reset threshold, V_{out} connects to V_{BATT} . Connect a 0.1µF capacitor from V_{out} to GND.
- Pin 3 V_{CC} +5V Input Supply Voltage.
- Pin 4 GND Ground reference for all signals.
- Pin 5 BATT ON Battery On Output. Goes high when V_{out} switches to V_{BATT} . Goes low when V_{out} switches to V_{cc} . Connect the base of a PNP through a current-limiting resistor to BATT ON for V_{out} current requirements greater than 250mA.
- Pin 6 LOWLINE Low Line Output. This output pin goes LOW when V_{cc} falls below the reset threshold voltage. This output pin returns to its HIGH output as soon as V_{cc} rises above the reset threshold voltage.

- Pin 7 OSC_{IN} External Oscillator Input. When OSC_{SEL} is unconnected or driven HIGH, a 10µA pull-up connects from V_{OUT} to this input pin, the internal oscillator sets the reset and watchdog timeout periods, and this input pin selects between fast and slow watchdog timeout periods. When OSC_{SEL} is driven LOW, the reset and watchdog timeout periods may be set either by a capacitor from this input pin to ground or by an external clock at this pin (refer to *Figure 21*).
- Pin 8 OSC_{SEL} Oscillator Select. When OSC_{SEL} is unconnected or driven HIGH, the internal oscillator sets the reset delay and watchdog timeout period. When OSC_{SEL} is driven LOW, the external oscillator input pin, OSC_{IN} , is enabled (refer to *Table 1*). This input pin has a 10µA internal pull-up.
- Pin 9 PFI Power-Fail Input. This is the noninverting input to the power-fail comparator. When PFI is less than 1.25V, PFO goes low. Connect PFI to GND or V_{OUT} when not used.
- Pin 10 PFO Power-Fail Output. This is the output of the power-fail comparator. PFO goes low when PFI is less than 1.25V. This is an uncommitted comparator, and has no effect on any other internal circuitry.
- Pin 11 WDI Watchdog Input. This is a three-level input pin. If WDI remains either HIGH or LOW for longer than the watchdog timeout period, WDO goes LOW and RESET is asserted for the reset timeout period. WDO remains LOW until the next transition at this input pin. Leaving this input pin unconnected disables the watchdog function. This input pin connects to an internal voltage divider between V_{OUT} and ground, which sets it to mid-supply when left unconnected.

- Pin 12 $\overline{CE_{OUT}}$ Chip-Enable Output. This output pin goes LOW only when $\overline{CE_{IN}}$ is LOW and V_{CC} is above the reset threshold voltage. If $\overline{CE_{IN}}$ is LOW when RESET is asserted, this output pin will stay low for 16µs or until $\overline{CE_{IN}}$ goes HIGH, whichever occurs first.
- Pin 13— $\overline{CE_{IN}}$ —Chip-Enable Input. This is the input pin to the chip-enable gating circuit. If this input pin is not used, connect it to ground or V_{OIIT} .
- Pin 14 WDO Watchdog Output. If WDI remains HIGH or LOW longer than the watchdog timeout period, this output pin goes LOW and RESET is asserted for the reset timeout period. This output pin returns HIGH on the next transition at WDI. This output pin remains HIGH if WDI is unconnected.

- Pin 15— $\overline{\text{RESET}}$ —Active LOW Reset Output. This output pin goes LOW whenever V_{CC} falls below the reset threshold. This output pin will remain low typically for 200ms after V_{CC} crosses the reset threshold voltage on power-up.
- Pin 16 RESET Active HIGH Reset Output. This output pin is open drain and the inverse of RESET.



Figure 16. Internal Block Diagram of the SP691A/693A/800L/800M



Figure 17. Typical Application Circuit of the SP691A/693A/800L/800M

- FEATURES

The SP691A/693A/800L/800M devices are microprocessor (µP) supervisory circuits that monitor the power supplied to digital circuits such as microprocessors, microcontrollers, or memory. The SP691A/693A/800L/800M series is an ideal solution for portable, batterypowered equipment that require power supply monitoring. The SP691A/693A/800L/800M watchdog functions will continuously oversee the operational status of a system. Implementing the SP691A/693A/800L/800M series will reduce the number of components and overall complexity in a design that requires power supply monitoring circuitry. The operational features and benefits of this series are described in more detail below.

-THEORY OF OPERATION

The **SP691A/693A/800L/800M** series is a complete μ P supervisor IC and provides the following main functions:

- µP reset → Reset output is asserted during power fluxiations such as power-up, power-down, and brown out conditions, and is guaranteed to be in the correct state for VCC down to 1V, even with no battery in the circuit.
- µP reset → Reset output is pulsed if the optional watchdog timer has not been toggled within a specified time.
- Power Fail Comparator → Provides for power-fail warning and low-battery detection, or monitors another power supply.

- 4) Watchdog function → Monitors µP activity where the watchdog output goes to a logic LOW state if the watchdog input is not toggled for greater than the timeout period.
- 5) Internal switch \Rightarrow Switches over from V_{CC} to V_{BATT} if the V_{CC} falls below the reset threshold.

RESET and **RESET** Outputs

The **SP691A/693A/800L/800M** devices' RESET and RESET outputs ensure that the μ P powers up in a known state, and prevents code-execution errors during power-down or brownout conditions.

The **RESET** output is active low, and typically sinks 3.2mA at 0.1V saturation voltage in its active state. When deasserted, $\overline{\text{RESET}}$ sources 1.6mA at typically VOUT - 0.5V. RESET output is open drain, active high, and typically sinks 3.2mA with a saturation voltage of 0.1V. When no backup battery is used, **RESET** output is guaranteed to be valid down to VCC = 1V, and an external $10k\Omega$ pull-down resistor on RESET ensures that **RESET** will be valid with VCC down to GND as shown on Figure 18. As VCC goes below 1V, the gate drive to the $\overline{\text{RESET}}$ output switch reduces accordingly, increasing the $R_{ps}(ON)$ and the saturation voltage. The $10k\Omega$ pull-down resistor ensures the parallel combination of switch plus resistor is around



Figure 18. External Pull-down Resistor Ensures \overline{RESET} is Valid with V_{CC} Down to Ground.

10k Ω and the output saturation voltage is below 0.4V while sinking 40µA. When using a 10k Ω external pull-down resistor, the high state for the RESET output with Vcc = 4.75V is 4.5V typical. For battery voltages less than or equal to 2V connected to VBATT, RESET and RESET remains valid for Vcc from 0V to 5.5V.

RESET and **RESET** are asserted when V_{cc} falls below the reset threshold and remain asserted for the Reset Timeout Period (200ms nominal) after V_{cc} rises above the reset threshold voltage on power-up. Refer to *Figure 19*. The devices' battery-switchover comparator does not affect reset assertion. However, both reset outputs are asserted in battery-backup mode since V_{cc} must be below the reset threshold to enter this mode.



Figure 19. Reset and Chip-Enable Timing



Figure 20. Watchdog Timeout Period and Reset Active Time

Watchdog Function

The watchdog monitors μ P activity via the Watchdog Input (WDI). If the μ P becomes inactive, RESET and RESET are asserted. To use the watchdog function, connect WDI to a bus line or μ P I/O line. If WDI remains high or low for longer than the watchdog timeout period (1.6s nominal). WDO, RESET, and RESET are asserted, indicating a software fault or idle conditions. Refer to **RESET and RESET Outputs** and **Watchdog Output** sections.

Watchdog Input

A change of logic state (minimum 100ns duration) at WDI during the watchdog period will reset the watchdog timer. The watchdog default timout is 1.6sec.

To disable the watchdog function, leave WDI floating. An internal resistor network $(100k\Omega]$ equivalent impedance at WDI) biases WDI to approximately 1.6V. Internal comparators detect this level and disable the watchdog timer. When Vcc is below the reset threshold, the watchdog function is disabled and WDI is disconnected from its internal resistor network, thus becoming high impedance.

Watchdog Output

WDO remains high if there is activity (transition or pulse) at WDI during the watchdog-timeout period. The watchdog function is disabled and WDO is a logic high when VCC is less than the reset threshold or when WDI is an open circuit. In watchdog mode, if no transition occurs at WDI during the watchdog-timeout period,



OSC	080	Watchdog	Poset Timeout Period	
	USC _{IN}	Normal	Immediately After Reset	Reset filleout i enou
LOW	External Clock Input	1024 clocks	4096 clocks	2048 clocks
LOW	External Capacitor	(600/47pF x C) ms	(2.4/47 pf x C) sec	(1200/47pF x C) ms
Floating	LOW	100 ms	1.6 s	200 ms
Floating	Floating	1.6 s	1.6 s	200 ms

 Table 1. Reset Pulse Width and Watchdog Timeout Selections

RESET and **RESET** are asserted for the reset timeout period (200ms nominal). WDO goes to logic low and remains low until the next transition at WDI. Refer to *Figure 20*. If WDI is held high or low indefinitely, **RESET** and **RESET** will generate 200ms pulses every 1.6s. WDO has a 2 x TTL output characteristic.

Selecting an Alternative Watchdog Timeout Period

The OSC_{SEL} and OSC_{IN} inputs control the watchdog are reset timeout periods. Floating OSC_{SEL} and OSC_{IN} or tying them both to V_{OUT} selects the nominal 1.6s watchdog timeout period and 200ms reset timout period. Connecting OSC_{IN} to ground and floating or connecting OSC_{SEL} to V_{OUT} selects a 100ms normal watchdog timeout period and a 1.6s timeout period immediately after reset. The reset timeout period remains 200ms. Refer to *Figure 20*. Select alternative timeout periods by connecting OSC_{SEL} to ground and connecting a capacitor between OSC_{IN} and ground, or by externally driving OSC_{IN}. A synopsis of this control can be found in *Figure 21* and *Table 1*.

Chip-Enable Signal Gating

The **SP691A/693A/800L/800M** devices provide internal gating of chip-enable (CE) signals, to prevent erroneous data from corrupting the CMOS RAM in the event of a power failure. During normal operation, the CE gate is enabled and passes all CE transitions. When reset is asserted, this path becomes disabled, preventing erroneous data from corrupting the CMOS RAM. The **SP691A/ 693A/800L/800M** devices use a series transmission gate from \overline{CE}_{IN} to \overline{CE}_{OUT} . Refer to *Figure 16*. The 10ns maximum CE propagation from \overline{CE}_{IN} to \overline{CE}_{OUT} enables the **SP691A/693A/800L/ 800M** devices to be used with most μ Ps.

Chip-Enable Input

 \overline{CE}_{IN} is in high impedance (disabled mode) while RESET and/or RESET are asserted.

During a power-down sequence where V_{CC} falls below the reset threshold, \overline{CE}_{IN} assumes a high impedance state when the voltage at \overline{CE}_{IN} goes high or 12µs after RESET is asserted, whichever occurs first. Refer to *Figure 19*. During a power-up sequence, CE_{IN} remains high impedance until RESET is deasserted.

In the high-impedance mode, the leakage currents into \overline{CE}_{IN} are $<1\mu A$ over temperature. In the low-impedance mode, the impedance of \overline{CE}_{IN} appears as a 65 Ω resistor in series with the load at \overline{CE}_{OUT} .

The propagation delay through the CE transmission gate depends on both the source impedance of the drive to \overline{CE}_{IN} and the capacitive loading on \overline{CE}_{OUT} (see the Chip-Enable Propagation Delay vs. \overline{CE}_{OUT} Load Capacitance graph in the **Typical Performance Characteristics** section). The CE propagation delay is defined from the 50% point on \overline{CE}_{IN} to the 50% point on \overline{CE}_{OUT} using a 50 Ω driver and 50pF of load capacitance as in *Figure 22*. For minimum propagation delay, minimize the capacitive load at \overline{CE}_{OUT} and use a low output-impedance driver.

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Figure 22. Chip Enable Propagation Delay Test Circuit



Figure 23. Low-Battery Indicator Circuit

Chip-Enable Output

In the enabled mode, the impedance of \overline{CE}_{OUT} is equivalent to 65Ω in series with the source driving \overline{CE}_{IN} . In the disabled mode, the 65Ω transmission gate is off and \overline{CE}_{OUT} is actively pulled to VOUT. This source turns off when the transmission gate is enabled.

LOWLINE Output

 $\overline{\text{LOWLINE}}$ is the buffered output pin of the reset threshold comparator. Refer to *Figure 16*. LOWLINE typically sinks 3.2mA at 0.1V. For normal operation where V_{CC} is above the reset threshold, LOWLINE is pulled to V_{OUT}.

Power-Fail Comparator

The power-fail comparator is an uncommitted comparator that has no effect on the other functions of the **SP691A/693A/800L/800M** devices. Common uses include low battery detection, as found in *Figure 23*, and early power-fail detection when the unregulated power is easily accessible as shown in *Figure 17*.

Power-Fail Input

The Power-Fail Input (PFI) has a guaranteed input leakage of ± 25 nA max over temperature. The typical comparator delay is 25µs from VIL to VOL (power failing), and 60µs from VIH to VOH (power being restored). Connect this input to ground if PFI is not used.

Power-Fail Output

The Power-Fail Output (\overline{PFO}) goes low when PFI goes below 1.25V. It sinks 3.2mA with a saturation voltage of 0.1V. With PFI above 1.25V, PFO is actively pulled to VOUT. PFO can be used to generate an NMI for the μ P, as shown in *Figure 17*.

Battery-Backup Mode

The **SP691A/693A/800L/800M** requires two conditions to switch to battery-backup mode: 1) VCC must be below the reset threshold; 2) VCC must be below VBATT. *Table 2* lists the status of the inputs and outputs in battery-backup mode.

Battery-On Output

The Battery On Output (BATT ON) indicates the status of the internal VCC/battery-switchover comparator, which controls the internal VCC and VBATT switches. For VCC greater that VBATT (ignoring the small hysteresis effect), BATT ON is a logic low. For $V_{\rm CC}$ less than $V_{\rm BATT}$, BATT ON is a logic high. Use BATT ON to indicate battery-switchover status or to supply base drive to an external pass transistor for higher-current applications. Refer to *Figure 17*.

NAME	STATUS	PIN NUMBER
V _{batt}	Supply current is 1µA maximum when V_{CC} <(V_{BATT} -1.2V).	1
V _{OUT}	$V_{_{OUT}}$ connected to $V_{_{BATT}}$ through an internal PMOS switch.	2
V _{cc}	Battery switchover comparator monitors $\rm V_{cc}$ for active switchover. $\rm V_{cc}$ is disconnected from $\rm V_{out}.$	3
GND	0V reference for all signals.	4
BATT ON	Logic HIGH. The open-circuit output voltage is equal to V_{out} .	5
LOWLINE	Logic LOW.	6
OSC	OSC_{IN} is ignored and is at high-Z.	7
OSC	OSC _{SEL} is ignored and is at high-Z.	8
PFI	The power-fail comparator is disabled.	9
PFO	The power-fail comparator is disabled. PFO is forced to logic LOW.	10
WDI	WDI is ignored and is at high-Z.	11
CE _{OUT}	Logic HIGH. The open-circuit output voltage is equal to V_{out}	12
	High-Z.	13
WDO	Logic HIGH. The open-circuit output voltage is equal to V_{out}	14
RESET	Logic LOW.	15
RESET	High-Z.	16

Table 2. Input and Output Status in Battery-Backup Mode; to enter the Battery-Backup Mode, V_{cc} must be less than the reset threshold and less than V_{RATT} .



Figure 24. V_{CC} and V_{BATT} to V_{OUT} Switch

Input Supply Voltage

The Input Supply Voltage (VCC) should be a regulated +5V source. VCC connects to VOUT via a parallel diode and a large PMOS switch. The switch carries the entire current load for currents less than 250mA. The parallel diode carries any current in excess of 250mA. Both the switch and the diode have impedances less than 1 Ω each. Refer to *Figure 24*. The maximum continuous current is 250mA, but power-on transients may reach a maximum of 1A.

Backup-Battery Input

The Backup-Battery Input (VBATT) is similar to VCC, except the PMOS switch and parallel diode are much smaller. Refer to *Figure 24*. Accordingly, the on-resistances of the diode and the switch are each approximately 10Ω .



Figure 25. High Capacity Capacitor on V_{BATT}

Continuous current should be limited to 25mA and peak currents (only during power-up) limited to 250mA. The reverse leakage of this input is less than 1µA over temperature and supply voltage.

Output Supply Voltage

The Output Supply Voltage (VOUT) supplies all the current to the external system and internal circuitry. All open-circuit outputs will assume the VOUT voltage in their high states rather than the VCC voltage. At the maximum source current of 250mA, VOUT will typically be 150mV below VCC. VOUT should be decoupled with 0.1µF capacitor.

TYPICAL APPLICATIONS

The **SP691A/693A/800L/800M** devices are not short-circuit protected. Shorting VOUT to ground, other than power-up transients such as charging a decoupling capacitor, may destroy the device. All open-circuit outputs swing between VOUT and GND rather than VCC and GND. If long leads connect to the chip inputs, ensure that these lines are free from ringing and other conditions that would forward bias the chip's protection diodes.

There are three distinct modes of operation:

1) Normal operating mode with all circuitry powered from V_{cc} . Typical supply current from V_{cc} is 35µA, while only leakage currents flow from the battery.

- 2) Battery-backup mode where V_{CC} is typically within 0.7V below V_{BATT} . All circuitry is powered from V_{BATT} and the supply current from the battery is typically less than 5µA.
- 3) Battery-backup mode where V_{CC} is less than V_{BATT} by at least 0.7V. V_{BATT} supply current is less than 1µA max.

Using High Capacity Capacitor with the SP691A/693A/800L/800M Series

VBATT has the same operating voltage range as VCC, and the battery-switchover threshold voltages are typically +30mV centered at VBATT, allowing use of a capacitor and a simple charging circuit as a backup source. Refer to *Figure 25*.

If VCC is above the reset threshold and VBATT is 0.5V above VCC, current flows to VOUT and VCC from VBATT until the voltage at VBATT is less than 0.5V above VCC.

Leakage current through the capacitor charging diode and **SP691A/693A/800L/800M** internal power diode eventually discharges the capacitor to VCC. Also, if VCC and VBATT start from 0.5V above the reset threshold and power is lost at VCC, the capacitor on VBATT discharges through VCC until VBATT reaches the reset threshold; the **SP691A/693A/800L/800M** devices then switch to battery-backup mode.

Using Separate Power Supplies for $\rm V_{BATT}$ and $\rm V_{cc}$

If using separate power supplies for VCC and VBATT, VBATT must be less than 0.3V above VCC when VCC is above the reset threshold. As described in the previous section, if VBATT exceeds this limit and power is lost at VCC, current flows continuously from VBATT to VCC via the VBATT-to-VOUT diode and the VOUT-to-VCC switch until the circuit is broken. Refer to *Figure 24*.

Alternative Chip-Enable Gating

Using memory devices with CE and \overline{CE} inputs allows the CE loop of the **SP691A/693A/800L/ 800M** series to be bypassed. To do this, connect \overline{CE}_{IN} to ground, pull up \overline{CE}_{OUT} to VOUT,

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Figure 26. Alternate Chip Enable Gating

and connect \overline{CE}_{OUT} to the \overline{CE} input of each memory device as shown in *Figure 26*. The CE input of each part then connects directly to the chip-select logic, which does not have to gated by the **SP691A/693A/800L/800M** devices.

Adding Hysteresis to the Power-Fail Comparator

Hysteresis adds noise margin to the power-fail comparator and prevents repeated triggering of PFO when V_{IN} is near the power-fail comparator trip point. *Figure 27* shows how to add hysteresis to the power-fail comparator. Select the ratio of R1 and R2 such that PFI sees 1.25V when V_{IN} falls to the desired trip point (V_{TRIP}). Resistor R3 adds hysteresis. It will typically be an order of magnitude greater than R1 or R2. The current through R1 and R2 should be at least 1µA to ensure that the 25nA (max) PFI input current does not shift the trip point. R3 should



Figure 27. Adding Hysteresis to the Power-Fail Comparator

be larger than $10k\Omega$ to prevent it from loading down the \overline{PFO} pin. Capacitor C1 adds additional noise rejection.

Monitoring a Negative Voltage

The power-fail comparator can be used to monitor a negative supply voltage using the circuit shown in *Figure 28*. When the negative supply is valid, \overrightarrow{PFO} is low. When the negative supply voltage drops, \overrightarrow{PFO} goes high. This circuit's accuracy is affected by the PFI threshold tolerance, the VCC voltage, and resistors R1 and R2.

Backup-Battery Replacement

The backup battery may be disconnected while VCC is above the reset threshold. No precautions are necessary to avoid spurious reset pulses.



Figure 28. Monitoring a Negative Voltage

Negative-Going V_{cc} Transients

While asserting resets to the μ P during power-up, power-down, and brownout conditions, these supervisors are relatively immune to shortduration negative-going VCC transients. It is usually undesirable to reset the μ P when VCC experiences only small glitches.

Refer to *Figure 29* for a graph of the maximum transient duration vs. the reset-comparator overdrive for which reset pulses are not generated. The graph was produced using negative-going pulses, starting at 5V and ending below the reset threshold by the magnitude indicated (reset comparator overdrive). The graph shows the maximum pulse width a negative-going VCC transient may typically have without causing a reset pulse to be issued.



Figure 29. Maximum Transient Duration Without Causing a Reset Pulse vs. Reset Comparator Overdrive

As the amplitude of the transient increases (i.e., goes farther below the reset threshold), the maximum allowable pulse width decreases. Typically, a VCC transient that goes 100mV below the reset threshold and lasts for $40\mu s$ or less will not cause a reset pulse to be issued. A 100nF bypass capacitor mounted close to the VCC pin provides additional transient immunity.

Connecting a Timing Capacitor to OSC

When OSC_{SEL} is connected to ground, OSC_{IN} disconnects from its internal 10µA pull-up and is internally connected to a ±100nA current source. When a capacitor is connected from OSC_{IN} to ground (to select an alternative watchdog timeout period), the current source charges and discharges the timing capacitor to create the oscillator that controls the reset and watchdog timeout period. To prevent timing errors, minimize external current leakage sources at this pin, and locate the capacitor as close to OSC_{IN} as possible. The sum of any PC board leakage plus the OSC capacitor leakage must be small compared to ±100nA.

Watchdog Software Considerations

A way to help the watchdog timer keep a closer watch on software execution involves setting and resetting the watchdog input at different points in the program, rather than "pulsing" the watchdog input high-low-high or low-high-low. This technique avoids a "stuck" loop where the watchdog timer continues to be reset within the loop, keeping the watchdog from timing out.

Figure 30 shows an example flow diagram where the I/O driving the watchdog input is set high at the beginning of the program, set low at the beginning of every subrouting or loop, then set high again when the program returns to the beginning. If the program should "hang" in any subroutine, the I/O is continually set low and the watchdog timer is allowed to time out, causing a reset or interrupt to be issued.

Maximum V_{cc} Fall Time

The VCC fall time is limited by the propagation delay of the battery switchover comparator and should not exceed $0.03 V/\mu s$. A standard rule of thumb for filter capacitance on most regulators is on the order of $100\mu F$ per amp of current. When the power supply is shut off or the main battery is disconnected, the associated initial VCC fall rate is just the inverse of $1A/100\mu F = 0.01 V/\mu s$. The VCC fall rate decreases with time as VCC falls exponentially, which more than satisfies the maximum fall-time requirement.



Figure 30. Watchdog Flow Diagram







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В◀			A
B◀	SE		w c



WITH PLATING

16 Pin NSOIC JEDEC MO-012 (AC) Variation							
SYMBOL	MIN	NOM	MAX				
A	1.35	-	1.75				
A1	0.1	-	0.25				
A2	1.25	-	1.65				
b	0.31	-	0.51				
С	0.17	-	0.25				
D	9.90 BSC						
E	6.00 BSC						
E1		3.90 BSC					
е		1.27 BSC					
L	0.4	-	1.27				
L1	1.04 REF						
L2	0.25 BSC						
ø	00	-	8º				
ø1	50	-	15°				

Note: Dimensions in (mm)







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A1 —	1			5	SIC	ΡE	VI	E١	N						Seati	ng Pla	ane



16 Pin SOIC JEDEC MS-013 (AA) Variation								
SYMBOL	MIN	NOM	MAX					
A	2.35	-	2.65					
A1	0.1	-	0.3					
A2	2.05	-	2.55					
b	0.31	-	0.51					
с	0.2	-	0.33					
D	10.30 BSC							
E	10.30 DSC							
E1	7.50 BSC							
e	1.27 BSC							
L	0.4	-	1.27					
L1	1.04 REF							
L2	2 0.25 BSC							
ø	0° - 8°							
ø1	50	-	150					

Note: Dimensions in (mm)

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eA	-
eB	

16 PIN PDI	16 PIN PDIP JEDEC MS-001 (BB) Variation								
SYMBOL	MIN	NOM	MAX						
A	-	-	0.21						
A1	0.15	-	-						
A2	0.115	0.13	0.195						
b	0.014	0.018	0.022						
b2	0.045	0.06	0.07						
b3	0.3	0.039	0.045						
с	0.008	0.01	0.014						
D	0.735	0.75	0.755						
D1	0.005	-	-						
E	0.3	0.31	0.325						
E1	0.24	0.25	0.28						
e .100 BSC									
eA	eA .300 BSC								
eB	-	-	0.43						
L	0.115	0.13	0.15						

Note: Dimensions in (mm)



ORDERING INFORMATION

Part Number	Temperature Range	Package Type
SP691ACP	0°C to +70°C	16-Pin PDIP
SP691ACN	0°C to +70°C	16-Pin NSOIC
SP691ACN/TR	0°C to +70°C	
SP691ACT	0°C to +70°C	16-Pin WSOIC
SP691ACT/TR	0°C to +70°C	16-Pin WSOIC
SP691AEP	-40°C to +85°C	16-Pin PDIP
SP691AEN	-40°C to +85°C	16-Pin NSOIC
SP691AEN/TR	-40°C to +85°C	16-Pin NSOIC
SP691AET	40°C to +85°C	16-Pin WSOIC
SP691AET/TR	40°C to +85°C	16-Pin WSOIC
SP693ACP	0°C to +70°C	16-Pin PDIP
SP693ACN	0°C to +70°C	
SP693ACN/TR	0°C to +70°C	
SP693ACT	0°C to +70°C	16-Pin WSOIC
SP693ACT/TR	0°C to +70°C	16-Pin WSOIC
SP693AEP	-40°C to +85°C	16-Pin PDIP
SP693AEN	-40°C to +85°C	16-Pin NSOIC
SP693AEN/TR	40°C to +85°C	16-Pin NSOIC
SP693AET	-40°C to +85°C	16-Pin WSOIC
SP693AET/TR	40°C to +85°C	16-Pin WSOIC
	and any T elevision and different strength and	

Available in lead free packaging. To order add "-L" suffix to part number.

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SP800LCP	0°C to +70°C	16-Pin PDIP
SP800LCN	0°C to +70°C	16-Pin NSOIC
SP800LCN/TR	0°C to +70°C	16-Pin NSOIC
SP800LCT	0°C to +70°C	16-Pin WSOIC
SP800LCT/TR	0°C to +70°C	16-Pin WSOIC
SP800LEP	-40°C to +85°C	16-Pin PDIP
SP800LEN	-40°C to +85°C	16-Pin NSOIC
SP800LEN/TR	-40°C to +85°C	16-Pin NSOIC
SP800LET	-40°C to +85°C	16-Pin WSOIC
SP800LET/TR	-40°C to +85°C	16-Pin WSOIC
SP800MCP		16-Pin PDIP
SP800MCN	0°C to +70°C	16-Pin NSOIC
SP800MCN/TR	0°C to +70°C	16-Pin NSOIC
SP800MCT	0°C to +70°C	16-Pin WSOIC
SP800MCT/TR	0°C to +70°C	16-Pin WSOIC
SP800MEP	-40°C to +85°C	16-Pin PDIP
SP800MEN	-40°C to +85°C	16-Pin NSOIC
SP800MEN/TR	-40°C to +85°C	16-Pin NSOIC
SP800MET	-40°C to +85°C	16-Pin WSOIC
SP800MET/TR	-40°C to +85°C	16-Pin WSOIC

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